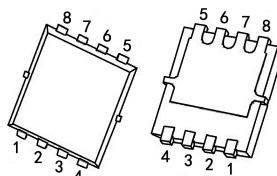


60V N-Channel Mosfet

**FEATURES**

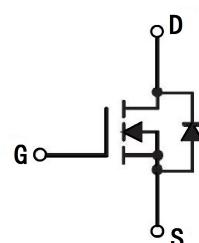
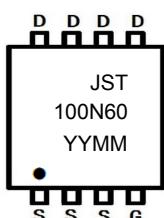
- $R_{DS(ON)} \leq 3m\Omega$  ( 2m $\Omega$  Typ.) @ $V_{GS}=10V$
- $R_{DS(ON)} \leq 4m\Omega$  ( 3m $\Omega$  Typ.) @ $V_{GS}=4.5V$
- AEC Q101 qualified
- Green Product (RoHS compliant)

**PDFNWB5\*6-8L**

1: S	3: S	5: D	7: D
2: S	4: G	6: D	8: D

**APPLICATIONS**

- Automobile wiper module
- Automotive domain controller
- PWM Applications
- Load Switch
- Power Management

**N-CHANNEL MOSFET****MARKING**

YYMM:Date Code(year &amp; month)

**MAXIMUM RATINGS (Tc=25°C unless otherwise noted)**

Symbol	Parameter	Limit.	Units
$V_{DSS}$	Drain-Source Voltage	60	V
$V_{GSS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Continuous Drain Current @ $V_{GS}=10V$ <sup>note1</sup>	105	A
$I_{DM}$	Pulsed Drain Current <sup>note2</sup>	420	A
$P_D$	Power Dissipation	60	W
$R_{eJC}$	Thermal Resistance, Junction to Case	2.5	°C/W
$T_J$	Operating Temperature	175	°C
$T_{STG}$	Storage Temperature Range	-55 to +175	°C

**MOSFET ELECTRICAL CHARACTERISTICS T<sub>c</sub>=25 °C unless otherwise specified**

<b>Symbol</b>	<b>Parameter</b>	<b>Test Condition</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>	<b>Units</b>
<b>Off Characteristic</b>						
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	60	-	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V, T <sub>J</sub> = 25°C	-	-	1	μA
I <sub>GSS</sub>	Gate to Body Leakage Current	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	-	-	±100	nA
<b>On Characteristics</b>						
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	1.0	-	3.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance <sup>note3</sup>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	-	2	3	mΩ
		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 20A	-	3	4	mΩ
<b>Dynamic Characteristics</b> <sup>note4</sup>						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1.0MHz	-	4894	-	pF
C <sub>oss</sub>	Output Capacitance		-	2208	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	171	-	pF
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> = 30V, I <sub>D</sub> = 25A V <sub>GS</sub> = 10V	-	99	-	nC
Q <sub>gs</sub>	Gate-Source Charge		-	16	-	nC
Q <sub>gd</sub>	Gate-Drain("Miller") Charge		-	27	-	nC
<b>Switching Characteristics</b> <sup>note4</sup>						
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 30V R <sub>G</sub> = 4.5Ω, I <sub>D</sub> = 25A R <sub>L</sub> = 1.2Ω	-	14	-	ns
t <sub>r</sub>	Turn-On Rise Time		-	36	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	75	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	50	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
V <sub>SD</sub>	Drain to Source Diode Forward Voltage	V <sub>GS</sub> = 0V, I <sub>SD</sub> = 20A T <sub>J</sub> = 25°C	-	-	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0V, I <sub>S</sub> = 25A, di/dt = 100A/μs	-	67	-	ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	90	-	nC

Notes:1. T<sub>C</sub>=25°C Limited only by maximum temperature allowed. Calculated continuous current based on maximum allowable junction temperature.

2. PW≤10μs, Duty cycle≤1%
- 3 . Pulse Test: Pulse width ≤ 300μs, Duty Cycle ≤ 2%
- 4 . Guaranteed by design, not subject to production testing

## TYPICAL PERFORMANCE CHARACTERISTICS

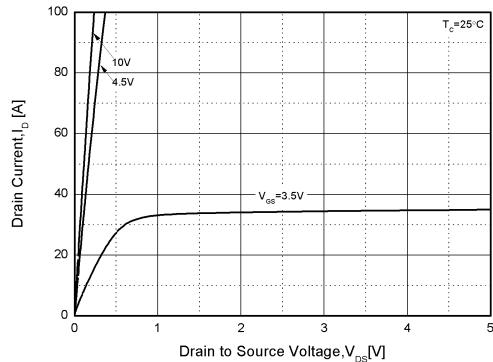


Figure1. Output Characteristics

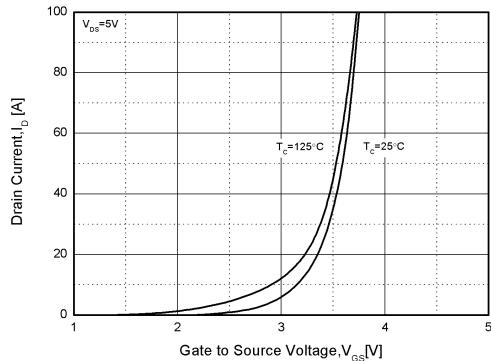


Figure2. Transfer Characteristics

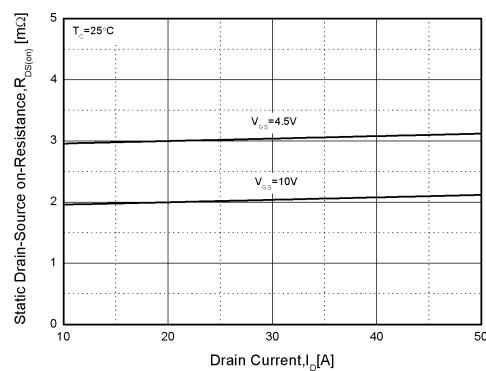


Figure3. Rdson-Drain Current

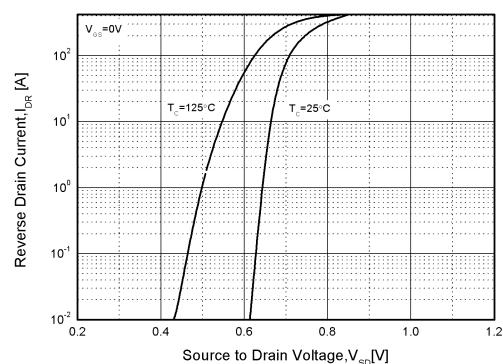


Figure4. Typical Source-Drain Diode Forward Voltage

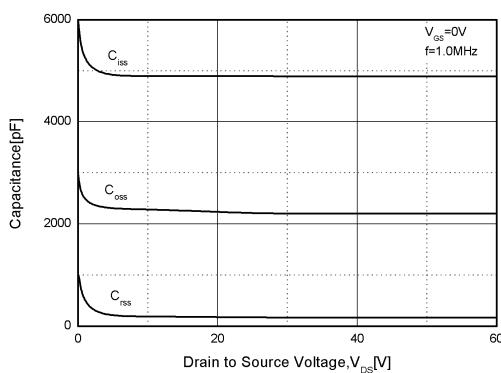


Figure5. Capacitance Characteristics

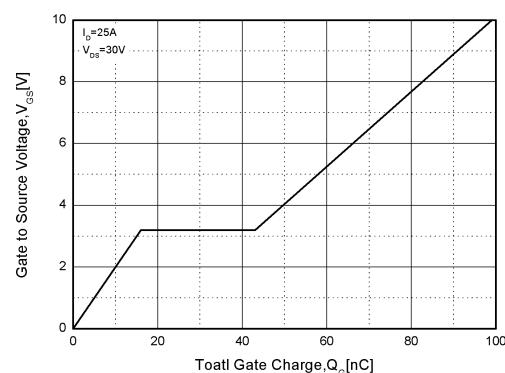


Figure6. Gate Charge

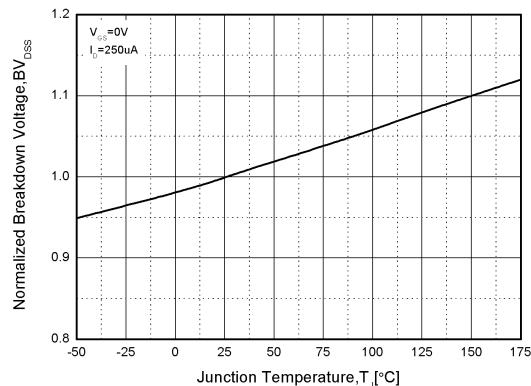
**TYPICAL PERFORMANCE CHARACTERISTICS (cont.)**


Figure7. Normalized Breakdown Voltage  
vs. Temperature

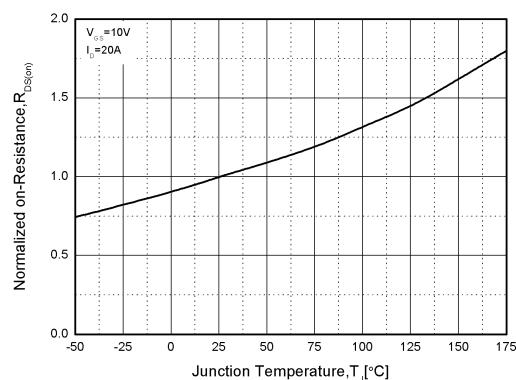


Figure8. Normalized on Resistance  
vs. Temperature

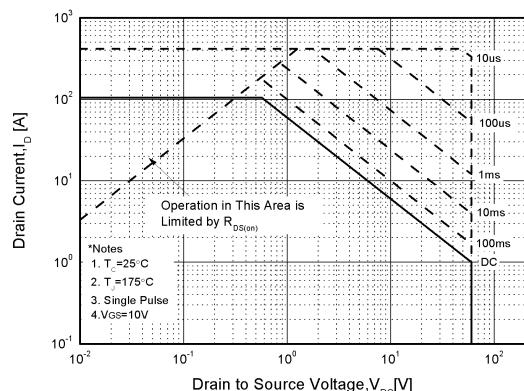


Figure9. Safe Operation Area

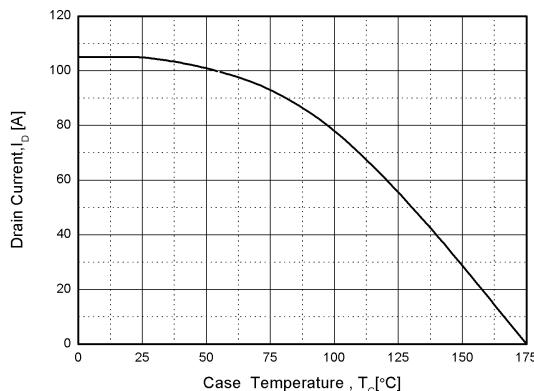


Figure10. Drain Current vs .Case Temperature

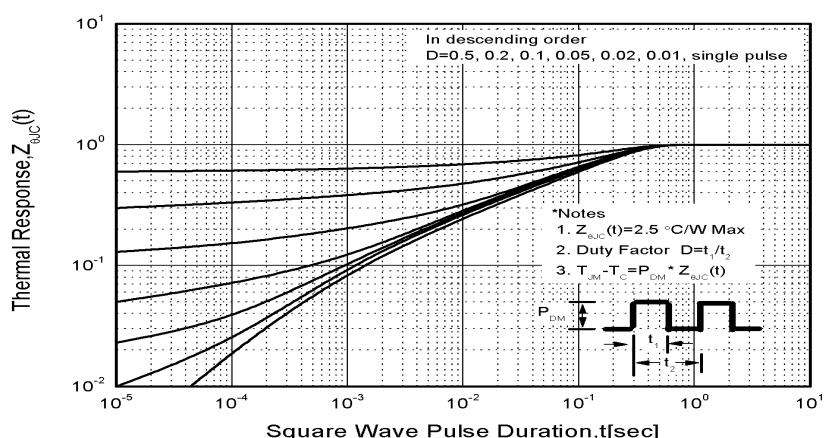
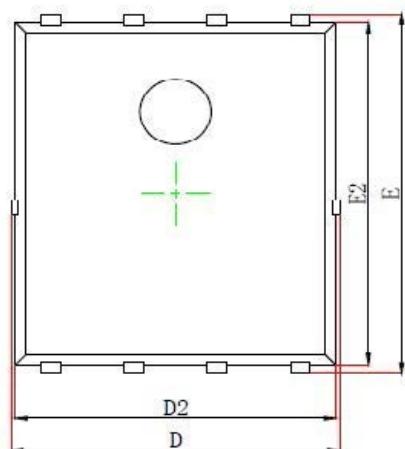
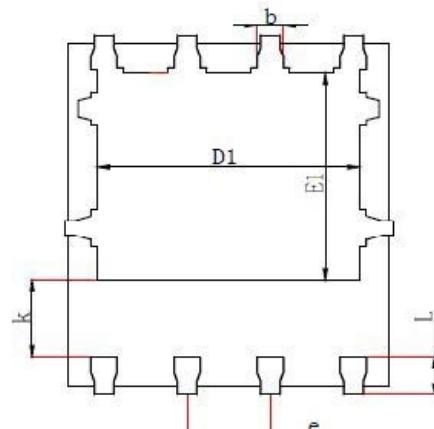


Figure11. Transient Thermal Response Curve

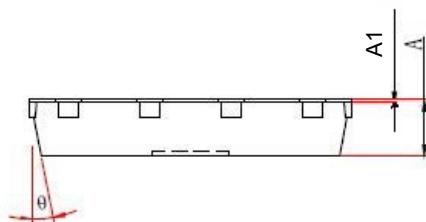
## PDFNWB5\*6-8L PACKAGE OUTLINE DRAWING



Top View  
[顶视图]



Bottom View  
[背视图]



Side View  
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.800	1.100	0.031	0.043
A1	0.000	0.05	0.000	0.002
D	-	5.4	-	0.212
E	-	6.200	-	0.244
D1	3.900	4.200	0.153	0.165
E1	3.350	3.650	0.132	0.144
D2	4.800	5.100	0.189	0.201
E2	5.674	5.950	0.223	0.234
k	1.100	1.500	0.043	0.059
b	0.250	0.490	0.010	0.019
e	1.170	1.370		
L	0.510	0.711	0.020	0.028
θ	6°	14°	6°	14°